

---

# APPENDIX B: Equation List

---

## B.1 I-V Model

### B.1.1 Threshold Voltage

$$\begin{aligned} V_{th} = & V_{th0} + K_1(\sqrt{\Phi_s - V_{bseff}} - \sqrt{\Phi_s}) - K_2 V_{bseff} \\ & + K_1 \left( \sqrt{1 + \frac{NLX}{L_{eff}}} - 1 \right) \sqrt{\Phi_s} + (K_3 + K_{3b} V_{bseff}) \frac{T_{ox}}{W_{eff}' + W_0} \Phi_s \\ & - D_{VT0w} \left( \exp\left(-D_{VT1w} \frac{W_{eff}' L_{eff}}{2l_{tw}}\right) + 2 \exp\left(-D_{VT1w} \frac{W_{eff}' L_{eff}}{l_{tw}}\right) \right) (V_{bi} - \Phi_s) \\ & - D_{VT0} \left( \exp\left(-D_{VT1} \frac{L_{eff}}{2l_t}\right) + 2 \exp\left(-D_{VT1} \frac{L_{eff}}{l_t}\right) \right) (V_{bi} - \Phi_s) \\ & - \left( \exp\left(-D_{sub} \frac{L_{eff}}{2l_{to}}\right) + 2 \exp\left(-D_{sub} \frac{L_{eff}}{l_{to}}\right) \right) (E_{tao} + E_{tab} V_{bseff}) V_{ds} \end{aligned}$$

$$l_t = \sqrt{\epsilon_{si} X_{dep} / C_{ox}} (1 + D_{VT2} V_{bseff})$$

$$l_{tw} = \sqrt{\epsilon_{si} X_{dep} / C_{ox}} (1 + D_{VT2w} V_{bseff})$$

$$l_{to} = \sqrt{\epsilon_{si} X_{dep0} / C_{ox}}$$

$$X_{dep} = \sqrt{\frac{2\epsilon_{si}(\Phi_s - V_{bseff})}{qN_{ch}}}$$

## I-V Model

---

$$X_{dep0} = \sqrt{\frac{2\epsilon_{si}\Phi_s}{qN_{ch}}}$$

( $\delta_1=0.001$ )

$$V_{bseff} = V_{bc} + 0.5[V_{bs} - V_{bc} - \delta_1 + \sqrt{(V_{bs} - V_{bc} - \delta_1)^2 - 4\delta_1 V_{bc}}]$$

$$V_{bc} = 0.9\left(\phi_s - \frac{K1^2}{4K2^2}\right)$$

$$V_{bi} = v_t \ln\left(\frac{N_{ch}N_{DS}}{n_i^2}\right)$$

### B.1.2 Effective Vgs-Vth

$$V_{gsteff} = \frac{2 n v_t \ln\left[1 + \exp\left(\frac{V_{gs} - V_{th}}{2 n v_t}\right)\right]}{1 + 2 n C_{ox} \sqrt{\frac{2\Phi_s}{q\epsilon_{si}N_{ch}}} \exp\left(-\frac{V_{gs} - V_{th} - 2V_{off}}{2 n v_t}\right)}$$

$$n = 1 + N_{factor} \frac{C_d}{C_{ox}} + \frac{(C_{dsc} + C_{dscd}V_{ds} + C_{dscb}V_{bseff})\left(\exp\left(-D_{VT1}\frac{L_{eff}}{2l}\right) + 2\exp\left(-D_{VT1}\frac{L_{eff}}{l}\right)\right)}{C_{ox}} + \frac{C_{it}}{C_{ox}}$$

$$C_d = \frac{\epsilon_{si}}{X_{dep}}$$

### B.1.3 Mobility

For Mobmod=1

## I-V Model

---

$$\mu_{eff} = \frac{\mu_o}{1 + (U_a + U_c V_{bseff}) \left( \frac{V_{gsteff} + 2V_{th}}{T_{ox}} \right) + U_b \left( \frac{V_{gsteff} + 2V_{th}}{T_{ox}} \right)^2}$$

For Mobmod=2

$$\mu_{eff} = \frac{\mu_o}{1 + (U_a + U_c V_{bseff}) \left( \frac{V_{gsteff}}{T_{ox}} \right) + U_b \left( \frac{V_{gsteff}}{T_{ox}} \right)^2}$$

For Mobmod=3

$$\mu_{eff} = \frac{\mu_o}{1 + \left[ U_a \left( \frac{V_{gsteff} + 2V_{th}}{T_{ox}} \right) + U_b \left( \frac{V_{gsteff} + 2V_{th}}{T_{ox}} \right)^2 \right] (1 + U_c V_{bseff})}$$

### B.1.4 Drain Saturation Voltage

For  $R_{ds} > 0$  or  $\lambda \neq 1$ :

$$V_{dsat} = \frac{-b - \sqrt{b^2 - 4ac}}{2a}$$

$$a = A_{bulk}^2 W_{eff} V_{sat} C_{ox} R_{DS} + \left( \frac{1}{\lambda} - 1 \right) A_{bulk}$$

## I-V Model

---

$$b = -\left( (V_{gsteff} + 2v_t) \left( \frac{2}{\lambda} - 1 \right) + A_{bulk} E_{sat} L_{eff} + 3A_{bulk} (V_{gsteff} + 2v_t) W_{eff} v_{sat} C_{ox} R_{DS} \right)$$

$$c = (V_{gsteff} + 2v_t) E_{sat} L_{eff} + 2(V_{gsteff} + 2v_t)^2 W_{eff} v_{sat} C_{ox} R_{DS}$$

$$\lambda = A_1 V_{gsteff} + A_2$$

For  $R_{ds}=0$ ,  $\lambda=1$ :

$$V_{dsat} = \frac{E_{sat} L_{eff} (V_{gsteff} + 2v_t)}{A_{bulk} E_{sat} L_{eff} + (V_{gsteff} + 2v_t)}$$

$$A_{bulk} = \left( 1 + \frac{K_1}{2\sqrt{\Phi_s - V_{bseff}}} \left\{ \frac{A_0 L_{eff}}{L_{eff} + 2\sqrt{X_j X_{dep}}} \left[ 1 - A_{gs} V_{gsteff} \left( \frac{L_{eff}}{L_{eff} + 2\sqrt{X_j X_{dep}}} \right)^2 \right] + \frac{B_0}{W_{eff} + B_1} \right\} \right) \frac{1}{1 + K_{ETA} V_{bseff}}$$

$$E_{sat} = \frac{2v_{sat}}{\mu_{eff}}$$

### B.1.5 Effective Vds

$$V_{dseff} = V_{dsat} - \frac{1}{2} \left( V_{dsat} - V_{ds} - \delta + \sqrt{(V_{dsat} - V_{ds} - \delta)^2 + 4\delta V_{dsat}} \right)$$

### B.1.6 Drain Current Expression

$$I_{ds} = \frac{I_{dso}(V_{dseff})}{1 + \frac{R_{ds}I_{dso}(V_{dseff})}{V_{dseff}}} \left(1 + \frac{V_{ds} - V_{dseff}}{V_A}\right) \left(1 + \frac{V_{ds} - V_{dseff}}{V_{ASCBE}}\right)$$

$$I_{dso} = \frac{W_{eff}\mu_{eff}C_{ox}V_{gsteff} \left(1 - A_{bulk} \frac{V_{dseff}}{2(V_{gsteff} + 2V_t)}\right)V_{dseff}}{L_{eff} [1 + V_{dseff} / (E_{sat}L_{eff})]}$$

$$V_A = V_{Asat} + \left(1 + \frac{P_{vag}V_{gsteff}}{E_{sat}L_{eff}}\right) \left(\frac{1}{V_{ACLM}} + \frac{1}{V_{ADIBLC}}\right)^{-1}$$

$$V_{ACLM} = \frac{A_{bulk}E_{sat}L_{eff} + V_{gsteff}}{P_{CLM}A_{bulk}E_{sat}l_{itl}} (V_{ds} - V_{dseff})$$

$$V_{ADIBLC} = \frac{(V_{gsteff} + 2V_t)}{\theta_{rout}(1 + P_{DIBLCB}V_{bseff})} \left(1 - \frac{A_{bulk}V_{dsat}}{A_{bulk}V_{dsat} + V_{gsteff} + 2V_t}\right)$$

$$\theta_{rout} = P_{DIBLC1} \left[ \exp\left(-D_{ROUT} \frac{L_{eff}}{2l_{i0}}\right) + 2 \exp\left(-D_{ROUT} \frac{L_{eff}}{l_{i0}}\right) \right] + P_{DIBLC2}$$

$$\frac{1}{V_{ASCBE}} = \frac{P_{scbe2}}{L_{eff}} \exp\left(\frac{-P_{scbe1}l_{itl}}{V_{ds} - V_{dseff}}\right)$$

$$V_{Asat} = \frac{E_{sat}L_{eff} + V_{dsat} + 2R_{DS}V_{sat}C_{ox}W_{eff}V_{gsteff} \left[1 - \frac{A_{bulk}V_{dsat}}{2(V_{gsteff} + 2V_t)}\right]}{2/\lambda - 1 + R_{DS}V_{sat}C_{ox}W_{eff}A_{bulk}}$$

$$l_{itl} = \sqrt{\frac{\epsilon_{si}T_{ox}X_j}{\epsilon_{ox}}}$$

### B.1.7 Substrate Current

$$I_{sub} = \frac{\alpha_o}{L_{eff}}(V_{ds} - V_{dseff}) \exp\left(-\frac{\beta_o}{V_{ds} - V_{dseff}}\right) \frac{I_{dso}}{1 + \frac{R_{ds}I_{dso}}{V_{dseff}}} \left(1 + \frac{V_{ds} - V_{dseff}}{V_A}\right)$$

### B.1.8 Polysilicon Depletion Effect

$$V_{poly} = \frac{1}{2} X_{poly} E_{poly} = \frac{qN_{gate} X_{poly}^2}{2\epsilon_{si}}$$

$$\epsilon_{ox} E_{ox} = \epsilon_{si} E_{poly} = \sqrt{2q\epsilon_{si}N_{gate} V_{poly}}$$

$$V_{gs} - V_{FB} - \phi_s = V_{poly} + V_{ox}$$

$$a(V_{gs} - V_{FB} - \phi_s - V_{poly})^2 - V_{poly} = 0$$

$$a = \frac{\epsilon_{ox}^2}{2q\epsilon_{si}N_{gate}T_{ox}^2}$$

$$V_{gs\_eff} = V_{FB} + \phi_s + \frac{q\epsilon_{si}N_{gate}T_{ox}^2}{\epsilon_{ox}^2} \left( \sqrt{1 + \frac{2\epsilon_{ox}^2(V_{gs} - V_{FB} - \phi_s)}{q\epsilon_{si}N_{gate}T_{ox}^2}} - 1 \right)$$

### B.1.9 Effective Channel Length and Width

$$L_{eff} = L_{drawn} - 2dL$$

$$W_{eff} = W_{drawn} - 2dW$$

$$W_{eff}' = W_{drawn} - 2dW'$$

$$dW = dW' + dW_g V_{gsteff} + dW_b (\sqrt{\phi_s - V_{bseff}} - \sqrt{\phi_s})$$

$$dW' = W_{int} + \frac{W_l}{L^{Wln}} + \frac{W_w}{W^{Wwn}} + \frac{W_{wl}}{L^{Wln} W^{Wwn}}$$

$$dL = L_{int} + \frac{L_l}{L^{Lln}} + \frac{L_w}{W^{Lwn}} + \frac{L_{wl}}{L^{Lln} W^{Lwn}}$$

### B.1.10 Drain/Source Resistance

$$R_{ds} = \frac{R_{dsw}[1 + P_{r\,wg}V_{gseff} + P_{r\,wb}(\sqrt{\phi_s - V_{bseff}} - \sqrt{\phi_s})]}{(10^6 W_{eff})^{Wr}}$$

### B.1.11 Temperature Effects

$$V_{th}(T) = V_{th}(T_{norm}) + (K_{T1} + K_{t1l} / L_{eff} + K_{T2}V_{bseff})(T / T_{norm} - 1)$$

$$\mu_o(T) = \mu_o(T_{norm})\left(\frac{T}{T_{norm}}\right)^{\mu_{tc}}$$

$$v_{sat}(T) = v_{sat}(T_{norm}) - A_T(T / T_{norm} - 1)$$

$$R_{dsw}(T) = R_{dsw}(T_{norm}) + P_{r\,t}\left(\frac{T}{T_{norm}} - 1\right)$$

$$U_a(T) = U_a(T_{norm}) + U_{a1}(T / T_{norm} - 1)$$

$$U_b(T) = U_b(T_{norm}) + U_{b1}(T / T_{norm} - 1)$$

$$U_c(T) = U_c(T_{norm}) + U_{c1}(T / T_{norm} - 1)$$

## B.2 Capacitance Model Equations

### B.2.1 Dimension Dependence

$$\delta W_{\text{eff}} = DWC + \frac{Wl}{L^{Wln}} + \frac{Ww}{W^{Wwn}} + \frac{Wwl}{L^{Wln}W^{Wwn}}$$

$$\delta L_{\text{eff}} = DLC + \frac{Ll}{L^{Lln}} + \frac{Lw}{W^{Lwn}} + \frac{Lwl}{L^{Lln}W^{Lwn}}$$

$$L_{\text{active}} = L_{\text{drawn}} - 2\delta L_{\text{eff}}$$

$$W_{\text{active}} = W_{\text{drawn}} - 2\delta W_{\text{eff}}$$

### B.2.2 Overlap Capacitance (for NMOS)

#### B.2.2.1 Source Overlap Capacitance

(1) for capmod=0

$$\frac{Q_{\text{overlap},s}}{W_{\text{active}}} = CGS0V_{gs}$$

(2) for capmod=1

## Capacitance Model Equations

---

if ( $V_{gs} < 0$ )

$$\frac{Q_{overlap,s}}{W_{active}} = C_{GS0}V_{gs} + \frac{C_{KAPPA}C_{GS1}}{2} \left( -1 + \sqrt{1 - \frac{4V_{gs}}{C_{KAPPA}}} \right)$$

else

$$\frac{Q_{overlap,s}}{W_{active}} = (C_{GS0} + C_{KAPPA}C_{GS1})V_{gs}$$

(3) for capmod=2

$$V_{gs,overlap} = \frac{1}{2} \left\{ (V_{gs} - \delta_1) + \sqrt{(V_{gs} - \delta_1)^2 - 4\delta_1} \right\} \quad \text{where } \delta_1 = 0.02$$

$$\frac{Q_{overlap,s}}{W_{active}} = C_{GS0}V_{gs} + C_{GS1} \left\{ V_{gs} - V_{gs,overlap} + \frac{C_{KAPPA}}{2} \left( -1 + \sqrt{1 + \frac{4V_{gs,overlap}}{C_{KAPPA}}} \right) \right\}$$

### B.2.2.2 Drain Overlap Capacitance

(1) for capmod=0

## Capacitance Model Equations

---

$$\frac{Q_{overlap,d}}{W_{active}} = CGD0V_{gd}$$

(2) for capmod=1

if ( $V_{gd} < 0$ )

$$\frac{Q_{overlap,d}}{W_{active}} = CGD0V_{gd} + \frac{CKAPPA C_{GD1}}{2} \left( -1 + \sqrt{1 - \frac{4V_{gd}}{CKAPPA}} \right)$$

else

$$\frac{Q_{overlap,d}}{W_{active}} = (CGD0 + CKAPPA C_{GD1}) V_{gd}$$

(3) for capmod=2

$$V_{gd,overlap} = \frac{1}{2} \left\{ (V_{gd} - \delta_2) + \sqrt{(V_{gd} - \delta_2)^2 - 4\delta_2} \right\} \quad \text{where } \delta_2 = 0.02$$

$$\frac{Q_{overlap,d}}{W_{active}} = CGD0V_{gd} + CGD1 \left\{ V_{gd} - V_{gd,overlap} + \frac{CKAPPA}{2} \left( -1 + \sqrt{1 + \frac{4V_{gd,overlap}}{CKAPPA}} \right) \right\}$$

### B.2.2.3 Gate Overlap Charge

$$Q_{\text{overlap,g}} = -(Q_{\text{overlap,s}} + Q_{\text{overlap,d}})$$

### B.2.3 Intrinsic Charges

(1) for capmod=0

a) Accumulation region ( $V_{gs} < V_{fb} + V_{bs}$ )

$$Q_g = W_{\text{active}} L_{\text{active}} C_{\text{ox}} (V_{gs} - V_{bs} - V_{fb})$$

$$Q_{\text{sub}} = -Q_g$$

$$Q_{\text{inv}} = 0$$

b) Subthreshold region ( $V_{gs} < V_{th}$ )

$$Q_b = -W_{\text{active}} L_{\text{active}} C_{\text{ox}} \frac{K_1^2}{2} \left( -1 + \sqrt{1 + \frac{4(V_{gs} - V_{fb} - V_{bs})}{K_1^2}} \right)$$

## Capacitance Model Equations

---

$$Q_g = -Q_b$$

$$Q_{inv} = 0$$

c) Strong inversion ( $V_{gs} > V_{th}$ )

$$V_{dsat,cv} = \frac{V_{gs} - V_{th}}{A_{bulk}'}$$

$$A_{bulk}' = A_{bulk0} \left( 1 + \left( \frac{CLC}{L_{eff}} \right)^{CLE} \right)$$

$$A_{bulk0} = \left( 1 + \frac{K_1}{2\sqrt{\Phi_s - V_{bs}}} \left\{ \frac{A_0 L_{eff}}{L_{eff} + 2\sqrt{X_j X_{dep}}} + \frac{B_0}{W_{eff}' + B_1} \right\} \right) \frac{1}{1 + K_{ETA} V_{bs}}$$

$$V_{th} = V_{fb} + \Phi_s + K_1 \sqrt{\Phi_s - V_{bsf}}$$

## Capacitance Model Equations

---

(i) 50/50 Charge partition

if  $V_{ds} < V_{dsat}$

$$Q_g = C_{ox} W_{active} L_{active} \left[ V_{gs} - V_{fb} - \Phi_s - \frac{V_{ds}}{2} + \frac{A_{bulk}' V_{ds}^2}{12(V_{gs} - V_{th} - \frac{A_{bulk}' V_{ds}}{2})} \right]$$

$$Q_{inv} = -W_{active} L_{active} C_{ox} \left[ V_{gs} - V_{th} - \frac{A_{bulk}' V_{ds}}{2} + \frac{A_{bulk}'^2 V_{ds}^2}{12(V_{gs} - V_{th} - \frac{A_{bulk}' V_{ds}}{2})} \right]$$

$$Q_b = W_{active} L_{active} C_{ox} \left[ V_{fb} - V_{th} + \Phi_s + \frac{(1 - A_{bulk}') V_{ds}}{2} - \frac{(1 - A_{bulk}') A_{bulk}' V_{ds}^2}{12(V_{gs} - V_{th} - \frac{A_{bulk}' V_{ds}}{2})} \right]$$

$$Q_s = Q_d = 0.5 Q_{inv} = -W_{active} L_{active} C_{ox} \left[ V_{gs} - V_{th} - \frac{A_{bulk}' V_{ds}}{2} + \frac{A_{bulk}'^2 V_{ds}^2}{12(V_{gs} - V_{th} - \frac{A_{bulk}' V_{ds}}{2})} \right]$$

otherwise

$$Q_g = W_{active} L_{active} C_{ox} \left( V_{gs} - V_{fb} - \Phi_s - \frac{V_{dsat}}{3} \right)$$

## Capacitance Model Equations

---

$$Q_s = Q_d = -\frac{I}{3} W_{active} L_{active} C_{ox} (V_{gs} - V_{th})$$

$$Q_b = -W_{active} L_{active} C_{ox} (V_{fb} + \Phi_s - V_{th} + \frac{(1 - A_{bulk}') V_{dsat}}{3})$$

(ii) 40/60 channel-charge Partition

if ( $V_{ds} < V_{dsat}$ )

$$Q_g = C_{ox} W_{active} L_{active} [V_{gs} - V_{fb} - \Phi_s - \frac{V_{ds}}{2} + \frac{A_{bulk}' V_{ds}^2}{12(V_{gs} - V_{th} - \frac{A_{bulk}' V_{ds}}{2})}]$$

$$Q_{inv} = -W_{active} L_{active} C_{ox} [V_{gs} - V_{th} - \frac{A_{bulk}' V_{ds}}{2} + \frac{A_{bulk}'^2 V_{ds}^2}{12(V_{gs} - V_{th} - \frac{A_{bulk}' V_{ds}}{2})}]$$

$$Q_b = W_{active} L_{active} C_{ox} [V_{fb} - V_{th} + \Phi_s + \frac{(1 - A_{bulk}') V_{ds}}{2} - \frac{(1 - A_{bulk}') A_{bulk}' V_{ds}^2}{12(V_{gs} - V_{th} - \frac{A_{bulk}' V_{ds}}{2})}]$$

## Capacitance Model Equations

---

$$Q_d = -W_{active} L_{active} C_{ox} \left[ \frac{V_{gs} - V_{th}}{2} - \frac{A_{bulk}'}{2} V_{ds} + \frac{A_{bulk}' V_{ds} \left[ \frac{(V_{gs} - V_{th})^2}{6} - \frac{A_{bulk}' V_{ds} (V_{gs} - V_{th})}{8} + \frac{(A_{bulk}' V_{ds})^2}{40} \right]}{(V_{gs} - V_{th} - \frac{A_{bulk}'}{2} V_{ds})^2} \right]$$

$$Q_s = -(Q_g + Q_b + Q_d)$$

otherwise

$$Q_g = W_{active} L_{active} C_{ox} (V_{gs} - V_{fb} - \Phi_s - \frac{V_{dsat}}{3})$$

$$Q_d = -\frac{4}{15} W_{active} L_{active} C_{ox} (V_{gs} - V_{th})$$

$$Q_s = -(Q_g + Q_b + Q_d)$$

$$Q_b = -W_{active} L_{active} C_{ox} (V_{fb} + \Phi_s - V_{th} + \frac{(1 - A_{bulk}') V_{dsat}}{3})$$

(iii) 0/100 Channel-charge Partition

if  $V_{ds} < V_{dsat}$

## Capacitance Model Equations

---

$$Q_g = C_{ox} W_{active} L_{active} \left[ V_{gs} - V_{fb} - \Phi_s - \frac{V_{ds}}{2} + \frac{A_{bulk}' V_{ds}^2}{12(V_{gs} - V_{th} - \frac{A_{bulk}' V_{ds}}{2})} \right]$$

$$Q_{inv} = -W_{active} L_{active} C_{ox} \left[ V_{gs} - V_{th} - \frac{A_{bulk}' V_{ds}}{2} + \frac{A_{bulk}'^2 V_{ds}^2}{12(V_{gs} - V_{th} - \frac{A_{bulk}' V_{ds}}{2})} \right]$$

$$Q_b = W_{active} L_{active} C_{ox} \left[ V_{fb} - V_{th} + \Phi_s + \frac{(1 - A_{bulk}') V_{ds}}{2} - \frac{(1 - A_{bulk}') A_{bulk}' V_{ds}^2}{12(V_{gs} - V_{th} - \frac{A_{bulk}' V_{ds}}{2})} \right]$$

$$Q_d = -W_{active} L_{active} C_{ox} \left[ \frac{V_{gs} - V_{th}}{2} + \frac{A_{bulk}' V_{ds}}{4} - \frac{(A_{bulk}' V_{ds})^2}{24(V_{gs} - V_{th} - \frac{A_{bulk}' V_{ds}}{2})} \right]$$

$$Q_s = -(Q_g + Q_b + Q_d)$$

otherwise

$$Q_g = W_{active} L_{active} C_{ox} (V_{gs} - V_{fb} - \Phi_s - \frac{V_{dsat}}{3})$$

## Capacitance Model Equations

---

$$Q_b = -W_{active} L_{active} C_{ox} (V_{fb} + \Phi_s - V_{th} + \frac{(1 - A_{bulk}') V_{dsat}}{3})$$

$$Q_d = 0$$

$$Q_s = -(Q_g + Q_b)$$

(2) for capmod=1

if ( $V_{gs} < V_{fb} + V_{bs} + V_{gsteffcv}$ )

$$Q_{g1} = -W_{active} L_{active} C_{ox} (V_{gs} - V_{fb} - V_{bs} - V_{gsteffcv})$$

else

$$Q_{g1} = W_{active} L_{active} C_{ox} \frac{K_1^2}{2} \left( -1 + \sqrt{1 + \frac{4(V_{gs} - V_{FB} - V_{gsteffcv} - V_{bs})}{K_1^2}} \right)$$

$$Q_{b1} = -Q_{g1}$$

## Capacitance Model Equations

---

$$V_{dsat,cv} = \frac{V_{gsteffcv}}{A_{bulk}'}$$

$$A_{bulk}' = A_{bulk0} \left( 1 + \left( \frac{CLC}{L_{eff}} \right)^{CLE} \right)$$

$$A_{bulk0} = \left( 1 + \frac{K_1}{2\sqrt{\Phi_s - V_{bseff}}} \left\{ \frac{A_0 L_{eff}}{L_{eff} + 2\sqrt{X_i X_{dep}}} + \frac{B_0}{W_{eff}' + B_1} \right\} \right) \frac{1}{1 + K_{ETA} V_{bseff}}$$

$$V_{gsteffcv} = n v_t \ln \left[ 1 + \exp\left(\frac{V_{gs} - V_{th}}{n v_t}\right) \right]$$

if ( $V_{ds} \leq V_{dsat}$ )

$$Q_g = Q_{g1} + W_{active} L_{active} C_{ox} \left( V_{gsteffcv} - \frac{V_{ds}}{2} + \frac{A_{bulk}' V_{ds}^2}{12 \left( V_{gsteffcv} - \frac{A_{bulk}'}{2} V_{ds} \right)} \right)$$

$$Q_b = Q_{b1} + W_{active} L_{active} C_{ox} \left( \frac{1 - A_{bulk}'}{2} V_{ds} - \frac{(1 - A_{bulk}') A_{bulk}' V_{ds}^2}{12 \left( V_{gsteffcv} - \frac{A_{bulk}'}{2} V_{ds} \right)} \right)$$

## Capacitance Model Equations

---

(i) 50/50 Channel-charge Partition

$$Q_s = Q_d = -\frac{W_{active} L_{active} C_{ox}}{2} \left( V_{gsteffcv} - \frac{A_{bulk}'}{2} V_{ds} + \frac{A_{bulk}'^2 V_{ds}^2}{12 \left( V_{gsteffcv} - \frac{A_{bulk}'}{2} V_{ds} \right)} \right)$$

(ii) 40/60 Channel-charge partition

$$Q_s = -\frac{W_{active} L_{active} C_{ox}}{2 \left( V_{gsteffcv} - \frac{A_{bulk}'}{2} V_{ds} \right)^2} \left( V_{gsteffcv}^3 - \frac{4}{3} V_{gsteffcv}^2 (A_{bulk}' V_{ds}) + \frac{2}{3} V_{gsteffcv} (A_{bulk}' V_{ds})^2 - \frac{2}{15} (A_{bulk}' V_{ds})^3 \right)$$

$$Q_d = -(Q_g + Q_b + Q_s)$$

(iii) 0/100 Channel-charge Partition

$$Q_s = -W_{active} L_{active} C_{ox} \left( \frac{V_{gsteffcv}}{2} + \frac{A_{bulk}' V_{ds}}{4} - \frac{(A_{bulk}' V_{ds})^2}{24 \left( V_{gsteffcv} - \frac{A_{bulk}'}{2} V_{ds} \right)} \right)$$

$$Q_d = -(Q_g + Q_b + Q_s)$$

## Capacitance Model Equations

---

if ( $V_{ds} > V_{dsat}$ )

$$Q_g = Q_{g1} + W_{active} L_{active} C_{ox} \left( V_{gsteffcv} - \frac{V_{dsat}}{3} \right)$$

$$Q_b = Q_{b1} - W_{active} L_{active} C_{ox} \frac{(V_{gsteffcv} - V_{dsat})}{3}$$

(i) 50/50 Channel-charge Partition

$$Q_s = Q_d = -\frac{W_{active} L_{active} C_{ox}}{3} V_{gsteffcv}$$

(ii) 40/60 Channel-charge Partition

$$Q_s = -\frac{2W_{active} L_{active} C_{ox}}{5} V_{gsteffcv}$$

$$Q_d = -(Q_g + Q_b + Q_s)$$

(iii) 0/100 Channel-charge Partition

$$Q_s = -W_{active} L_{active} C_{ox} \frac{2V_{gsteffcv}}{3}$$

## Capacitance Model Equations

---

$$Q_d = -(Q_g + Q_b + Q_s)$$

(3) for capmod=2

$$Q_g = -(Q_{inv} + Q_{acc} + Q_{sub0} + \delta Q_{sub})$$

$$Q_b = Q_{acc} + Q_{sub0} + \delta Q_{sub}$$

$$Q_{inv} = Q_s + Q_d$$

$$V_{FBeff} = vfb - 0.5 \left\{ V_3 + \sqrt{V_3^2 + 4\delta_3 vfb} \right\} \quad \text{where} \quad V_3 = vfb - V_{gb} - \delta_3; \quad \delta_3 = 0.02$$

$$vfb = V_{th} - \phi_s - K_1 \sqrt{\phi_s}$$

$$Q_{acc} = -W_{active} L_{active} C_{ox} (V_{FBeff} - vfb)$$

$$Q_{sub0} = -W_{active} L_{active} C_{ox} \frac{K_1^2}{2} \left( -1 + \sqrt{1 + \frac{4(V_{gs} - V_{FBeff} - V_{gsteff,cv} - V_{bseff})}{K_1^2}} \right)$$

$$V_{dsat,cv} = \frac{V_{gsteff,cv}}{A_{bulk}}$$

## Capacitance Model Equations

---

$$A_{bulk}' = A_{bulk0} \left( 1 + \left( \frac{CLC}{L_{active}} \right)^{CLE} \right)$$

$$A_{bulk0} = \left( 1 + \frac{K_1}{2\sqrt{\Phi_s - V_{bseff}}} \left\{ \frac{A_0 L_{eff}}{L_{eff} + 2\sqrt{X_l X_{dep}}} + \frac{B_0}{W_{eff}' + B_1} \right\} \right) \frac{1}{1 + K_{ETA} V_{bseff}}$$

$$V_{gsteffcv} = n v_t \ln \left[ 1 + \exp \left( \frac{V_{gs} - V_{th}}{n v_t} \right) \right]$$

$$V_{cveff} = V_{dsat,cv} - 0.5 \left\{ V_4 + \sqrt{V_4^2 + 4\delta_4 V_{dsat,cv}} \right\} \quad \text{where} \quad V_4 = V_{dsat,cv} - V_{ds} - \delta_4; \quad \delta_4 = 0.02$$

$$Q_{inv} = -W_{active} L_{active} C_{ox} \left( \left( V_{gsteffcv} - \frac{A_{bulk}'}{2} V_{cveff} \right) + \frac{A_{bulk}'^2 V_{cveff}^2}{12 \left( V_{gsteffcv} - \frac{A_{bulk}'}{2} V_{cveff} \right)} \right)$$

$$\delta Q_{sub} = W_{active} L_{active} C_{ox} \left( \frac{1 - A_{bulk}'}{2} V_{cveff} - \frac{(1 - A_{bulk}') A_{bulk}' V_{cveff}^2}{12 \left( V_{gsteffcv} - \frac{A_{bulk}'}{2} V_{cveff} \right)} \right)$$

### B.2.3.1 50/50 Charge partition

## Capacitance Model Equations

---

$$Q_s = Q_d = 0.5Q_{inv} = -\frac{W_{active} L_{active} C_{ox}}{2} \left( V_{gsteffcv} - \frac{A_{bulk}}{2} V_{cveff} + \frac{A_{bulk}^2 V_{cveff}^2}{12 \left( V_{gsteffcv} - \frac{A_{bulk}}{2} V_{cveff} \right)} \right)$$

### B.2.3.2 40/60 Channel-charge Partition

$$Q_s = -\frac{W_{active} L_{active} C_{ox}}{2 \left( V_{gsteffcv} - \frac{A_{bulk}}{2} V_{cveff} \right)^2} \left( V_{gsteffcv}^3 - \frac{4}{3} V_{gsteffcv}^2 (A_{bulk} V_{cveff}) + \frac{2}{3} V_{gsteffcv} (A_{bulk} V_{cveff})^2 - \frac{2}{15} (A_{bulk} V_{cveff})^3 \right)$$

$$Q_d = -\frac{W_{active} L_{active} C_{ox}}{2 \left( V_{gsteffcv} - \frac{A_{bulk}}{2} V_{cveff} \right)^2} \left( V_{gsteffcv}^3 - \frac{5}{3} V_{gsteffcv}^2 (A_{bulk} V_{cveff}) + V_{gsteffcv} (A_{bulk} V_{cveff})^2 - \frac{1}{5} (A_{bulk} V_{cveff})^3 \right)$$

### B.2.3.3 0/100 Charge Partition

$$Q_s = -W_{active} L_{active} C_{ox} \left( \frac{V_{gsteffcv}}{2} + \frac{A_{bulk} V_{cveff}}{4} - \frac{(A_{bulk} V_{cveff})^2}{24 \left( V_{gsteffcv} - \frac{A_{bulk}}{2} V_{cveff} \right)} \right)$$

$$Q_d = -W_{active} L_{active} C_{ox} \left( \frac{V_{gsteffcv}}{2} - \frac{3A_{bulk} V_{cveff}}{4} + \frac{(A_{bulk} V_{cveff})^2}{8 \left( V_{gsteffcv} - \frac{A_{bulk}}{2} V_{cveff} \right)} \right)$$

## NQS Model Equations:

---

### B.2.4 Intrinsic Capacitances (with Body bias and DIBL)

$$C_{(s,d,g,b),g} = \frac{\partial Q_{s,d,g,b}}{\partial V_{gsteffcv}} \frac{\partial V_{gsteffcv}}{\partial V_{gt}}$$

$$C_{(s,d,g,b),s} = -\frac{\partial Q_{s,d,g,b}}{\partial V_{ds}} + \frac{\partial Q_{s,d,g,b}}{\partial V_{gsteffcv}} \frac{\partial V_{gsteffcv}}{\partial V_{gt}} \left( \frac{\partial V_{th}}{\partial V_{ds}} + \frac{\partial V_{th}}{\partial V_{bs}} \right)$$

$$C_{(s,d,g,b),d} = \frac{\partial Q_{s,d,g,b}}{\partial V_{ds}} - \frac{\partial Q_{s,d,g,b}}{\partial V_{gsteffcv}} \frac{\partial V_{gsteffcv}}{\partial V_{gt}} \frac{\partial V_{th}}{\partial V_{ds}}$$

$$C_{(s,d,g,b),b} = \frac{\partial Q_{s,d,g,b}}{\partial V_{bs}} - \frac{\partial Q_{s,d,g,b}}{\partial V_{gsteffcv}} \frac{\partial V_{gsteffcv}}{\partial V_{gt}} \frac{\partial V_{th}}{\partial V_{bs}}$$

## B.3 NQS Model Equations:

Quasi-static equilibrium channel charge:

$$Q_{eq} = -(Q_g + Q_b)$$

Actual channel charge and  $Q_{def}$  obtained from subcircuit (Figure 5-2):

$$Q_{ch} = Q_{eq} - Q_{def}$$

$$g_{\tau} = \frac{1}{\tau} = \frac{1}{\tau_{drift}} + \frac{1}{\tau_{diff}}$$

## Flicker Noise

---

$$\tau_{drift} = \frac{C_{ox} W_{eff} L_{eff}^3}{\mu_{eff} \varepsilon |Q_{eq} - \alpha Q_{def}|} \approx \frac{\zeta}{|Q_{eq}|}$$

where,

$$\varepsilon \equiv \text{Elmore Constant (default = 5)} \quad 0.0 \leq \alpha \leq 1.0 \text{ (default = 0.5)}$$

and

$$\zeta = \frac{C_{ox} W_{eff} L_{eff}^3}{\mu_{eff} \varepsilon}$$

$$\tau_{diff} = \frac{q L_{eff}^2}{16 \mu_{eff} K T}$$

## B.4 Flicker Noise

There exists two models for flicker noise. Each of these can be toggled by the **noimod** flag.

1. For noimod=1 and 4

$$\text{Flicker Noise} = \frac{K_f I_{ds}^{af}}{C_{ox} L_{eff}^2 f^{ef}}$$

2. For noimod=2 and 3

1.  $V_{gs} > V_{th} + 0.1$ :

$$\begin{aligned} \text{Flicker Noise} = & \frac{vtq^2 I_{ds} \mu_{eff}}{f^{Ef} L_{eff}^2 C_{ox} 10^8} \left[ N_{oia} \log\left(\frac{No + 2x10^{14}}{Nl + 2x10^{14}}\right) + N_{oib}(No - Nl) \right. \\ & \left. + 0.5 N_{oic}(No^2 - Nl^2) \right] + \frac{vt I_{ds}^2 \Delta L_{clm}}{f^{Ef} L_{eff}^2 W_{eff} 10^8} \frac{N_{oia} + N_{oib} Nl + N_{oic} Nl^2}{(Nl + 2x10^{14})^2} \end{aligned}$$

## Flicker Noise

---

where  $V_{tm}$  is the thermal voltage,  $\mu_{eff}$  is the effective mobility at the given bias condition,  $L_{eff}$  and  $W_{eff}$  are the effective channel length and width, respectively. The parameter  $N_0$  is the charge density at the source given by:

$$N_0 = \frac{C_{ox}(V_{GS} - V_{TH})}{q}$$

The parameter  $N_l$  is the charge density at the drain given by:

$$N_l = \frac{C_{ox}(V_{GS} - V_{TH} - V_{DS}')}{q}$$

$$V_{DS}' = \text{MIN}(V_{DS}, V_{DSAT})$$

$\Delta L_{clm}$  refers to channel length reduction due to CLM and is given by:

$$\Delta L_{clm} = \begin{cases} \text{Litl} \times \log \left( \frac{V_{DS} - V_{DSAT}}{\text{Litl}} + Em \right) & \text{if } V_{DS} > V_{DSAT} \\ 0 & \text{otherwise} \end{cases}$$

$$E_{SAT} = \frac{2 \times V_{sat}}{u_{eff}}$$

2. Otherwise,

## Channel Thermal Noise

---

$$FlickerNoise = \frac{S_{limit} \times S_{wi}}{S_{limit} + S_{wi}}$$

Where,  $S_{limit}$  is the flicker noise calculated at  $V_{gs}=V_{th}+0.1$  and  $S_{wi}$  is given by:

$$S_{wi} = \frac{Noia Vt I_{ds}^2}{W_{eff} L_{eff} f^{Ef} 4x10^{36}}$$

## B.5 Channel Thermal Noise

There exists two models for channel thermal noise. Each of these can be toggled by the **noimod** flag.

1. For noimod=1 and 3

$$\frac{8kT}{3} (gm + gds + gmb)$$

2. For noimod=2 and 4

$$\frac{4KT\mu_{eff}}{L_{eff}^2} |Q_{inv}|$$

$$Q_{inv} = -W_{eff} L_{eff} C_{ox} V_{gsteff} \left(1 - \frac{A_{bulk}}{2(V_{gsteff} + 2vt)} V_{dseff}\right)$$

## Channel Thermal Noise

---

The derivation for this last thermal noise expression is based on the noise model found in [35].

















